



Features

- I_{L} \leq $10A$, $V_{DSS} \geq -40V$, $V_{GS} \geq 10V$
- $U_{GDS} \leq 10V$, $I_D \leq 10A$
- $S_{on} \leq 0.5\mu s$
- $Y_{DS} \geq 100mV/V$
- $S_{off} \leq 100nA$
- $Q_{SS} \leq 10nC$



IEC Compatibility (EN61000-4)

- IEC 61000-4-2 (ESD) $\pm 30kV$ (air), $\pm 30kV$ (contact)
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 9A (8/20 μs)

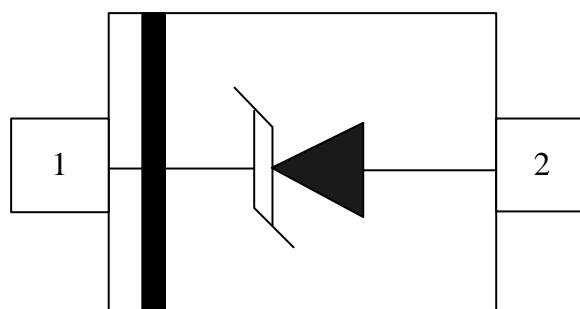
Mechanical Characteristics

- $U_{GDS} \leq 10V$
- $T_{J} \leq 150^{\circ}C$
- $U_{GDS} \leq 10V$, $I_D \leq 10A$
- $U_{GDS} \leq 10V$, $I_D \leq 10A$

Applications

- $I_{L} \leq 10A$, $V_{DSS} \geq -40V$
- $U_{GDS} \leq 10V$, $I_D \leq 10A$
- $P_{diss} \leq 10W$
- $U_{GDS} \leq 10V$, $I_D \leq 10A$
- $Q_{SS} \leq 10nC$
- $T_{J} \leq 150^{\circ}C$

Schematic & PIN Configuration



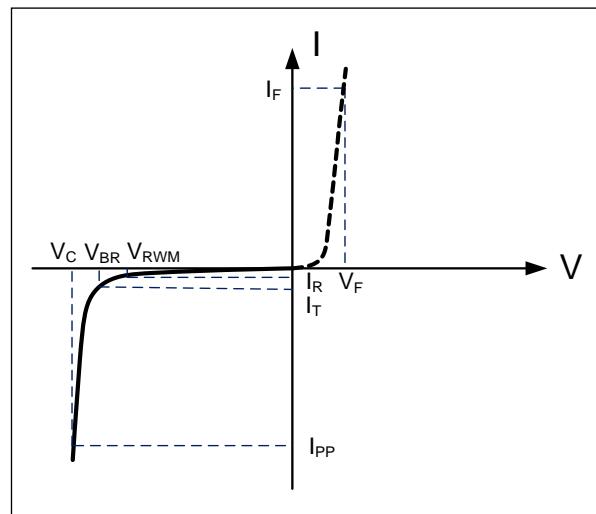


Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power ($t_p = 8/20\mu s$)	P_{PP}	504	Watts
Peak Pulse Current ($t_p = 8/20\mu s$)	I_{pp}	9	A
Operating Temperature	T_J	-55 to +125	°C
Storage Temperature	T_{STG}	-55 to +150	°C

Electrical Parameters (T=25°C)

Symbol	Parameter
I_{PP}	Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
V_{RWM}	Reverse Stand-Off Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_F	Forward Current
V_F	Forward Voltage @ I_F



Electrical Characteristics

DW24D5-AT-E						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	V_{RWM}				24	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1\text{mA}$	26.7			V
Reverse Leakage Current	I_R	$V_{RWM}=24\text{V}, T=25^\circ\text{C}$			500	nA
Forward Voltage	V_F	$I_F=10\text{mA}$	0.6		1	V
Clamping Voltage	V_C	$I_{PP} = 9\text{A}, t_p = 8/20\mu\text{s}$		52	56	V
Dynamic Resistance ^{1,2}	R_{DYN}	$\text{TLP}=0.2/100\text{ns}$		0.4		Ω
ESD Clamping Voltage ¹	V_C	$\text{IPP} = 4\text{A}, t_p = 0.2/100\text{ns} (\text{TLP})$		33		V
ESD Clamping Voltage ¹	V_C	$\text{IPP} = 16\text{A}, t_p = 0.2/100\text{ns} (\text{TLP})$		37.7		V
Junction Capacitance	C_J	$V_R = 0\text{V}, f = 1\text{MHz}$		45	50	pF

Notes : 1、TLP Setting : $t_p=100\text{ns}$, $t_i=0.2\text{ns}$, I_{TLP} and V_{TLP} sample window: $t_1=70\text{ns}$ to $t_2=90\text{ns}$.

2、Dynamic resistance calculated from $I_{PP}=4\text{A}$ to $I_{PP}=16\text{A}$ using "Best Fit".

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Typical Characteristics

Figure 1: Peak Pulse Power vs. Pulse Time

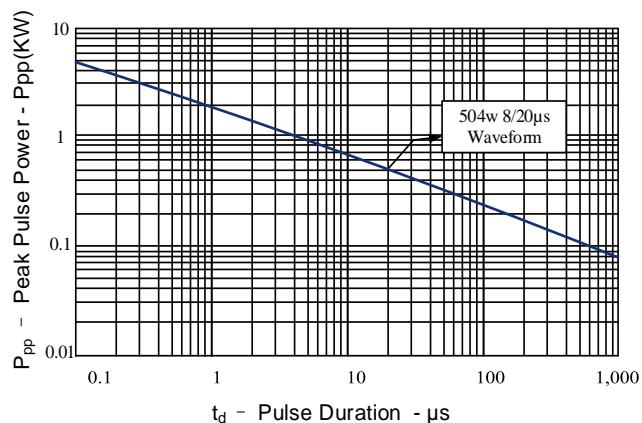


Figure 2: Power Derating Curve

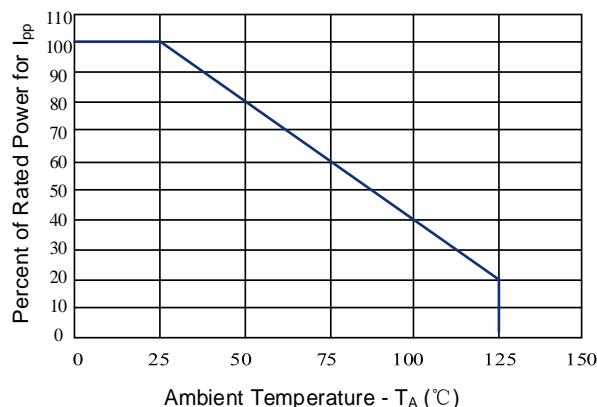


Figure 3: Clamping Voltage vs. Peak Pulse Current

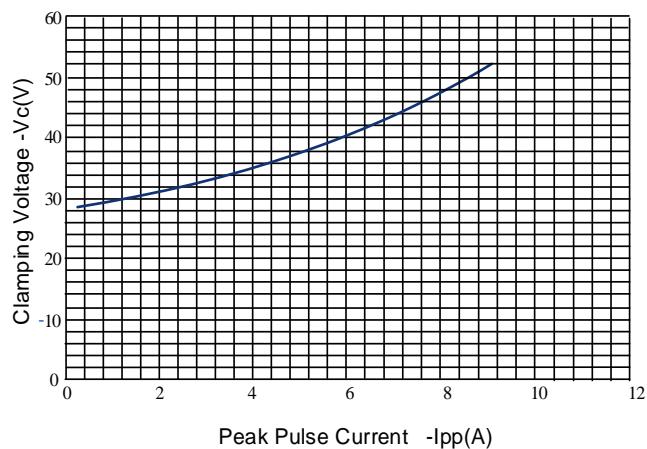


Figure 4: Normalized Junction Capacitance vs. Reverse Voltage

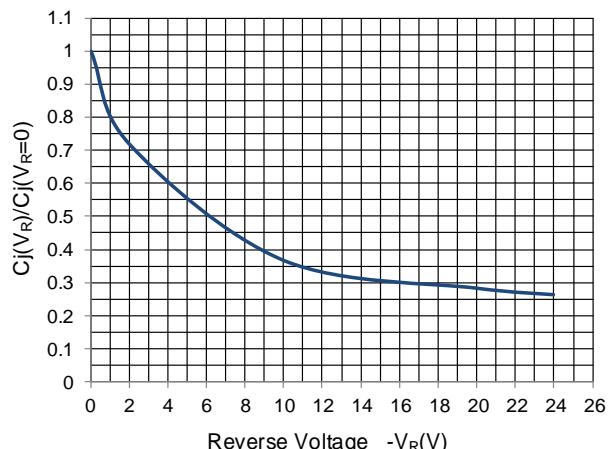


Figure 5: 8/20μs Pulse Waveform

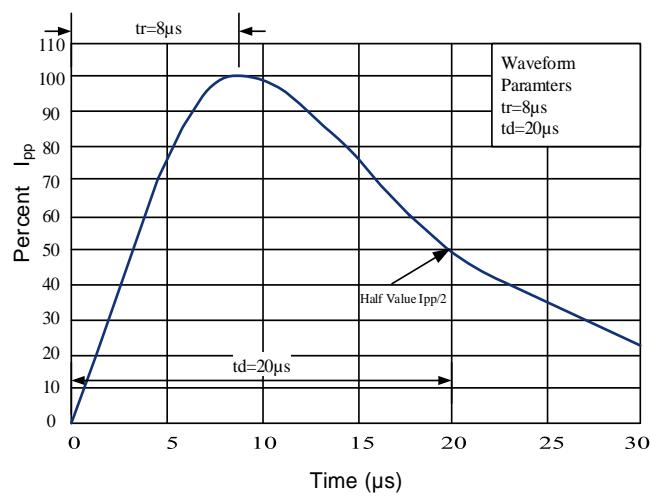
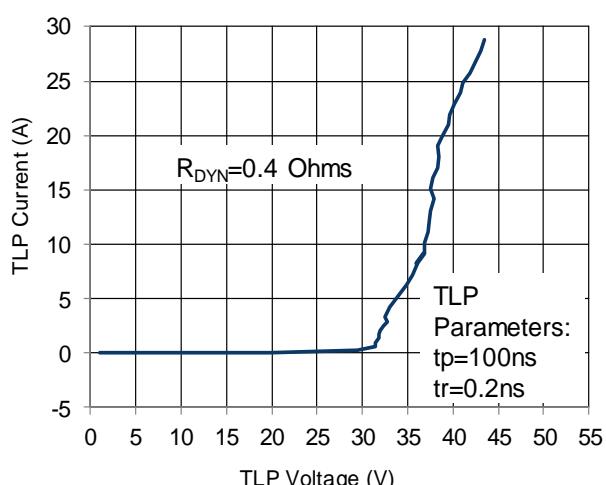


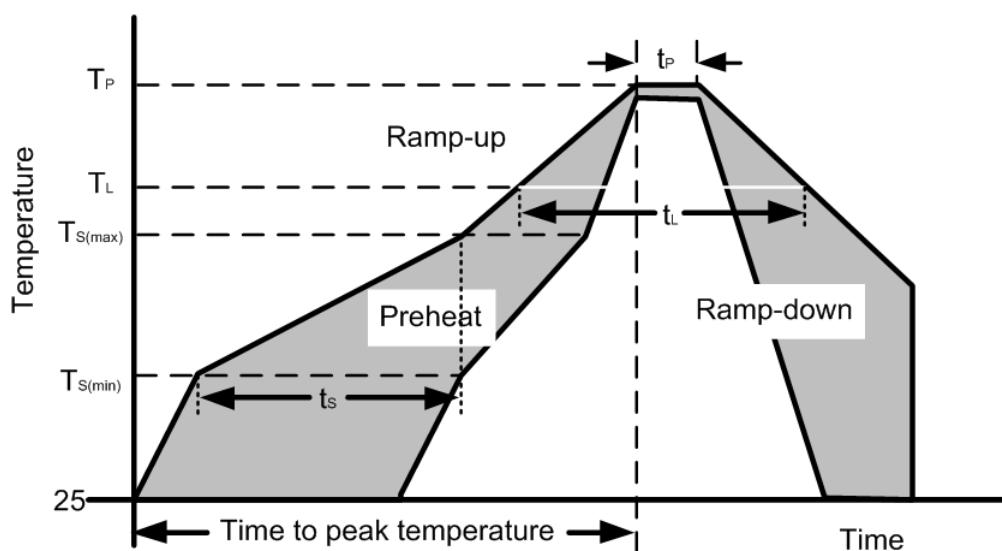
Figure 6: TLP I-V Curve





Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	Temperature Min ($T_{s(\min)}$)	150°C
	Temperature Max ($T_{s(\max)}$)	200°C
	Time (min to max) (ts)	60 – 190 secs
Average ramp up rate (Liquidus Temp) (T_L) to peak		5°C/second max
$T_{s(\max)}$ to T_L —Ramp-up Rate		5°C/second max
Reflow	Temperature (T_L) (Liquidus)	217°C
	Temperature (t_L)	60 – 150 seconds
	Peak Temperature (T_P)	260+0/-5 °C
Time within actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature (T_P)		8 minutes Max.
Do not exceed		280°C





Outline Drawing –SOD-523

PACKAGE OUTLINE				
DIMENSIONS				
SYMBOL		MILLIMETERS		INCHES
		MIN	MAX	MIN
A		0.50	0.70	0.020
A1		0.00	0.07	0.000
b		0.25	0.35	0.010
C		0.07	0.20	0.003
D		1.10	1.30	0.043
E		0.70	0.90	0.028
H _E		1.50	1.70	0.059
L		0.15	0.25	0.006
DIMENSIONS: MILLIMETERS				
Notes: Controlling Dimension: Millimeter.				

Marking Codes

Part Number	Marking Code
DW24D5-AT-E	

Package Information

Qty: 5k/Reel